



“XE30” Series

High Reliability Hybrid Microcircuit Crystal Oscillators

5.0V TTL, 5.0V HC/ACMOS, 3.3V, 2.5V & 1.8V LVHCMOS

Features

- Ruggedized 4 Point Crystal Mount
- Tristate Output Option
- Radiation Tolerant to 10K Rads
- Low Profile Surface Mount, 0.140” Max. Height
- 100% Screening Options
- Low Phase Noise
- Hermetically Sealed, Ceramic Package
- Made in USA, ECCN: EAR99

Applications

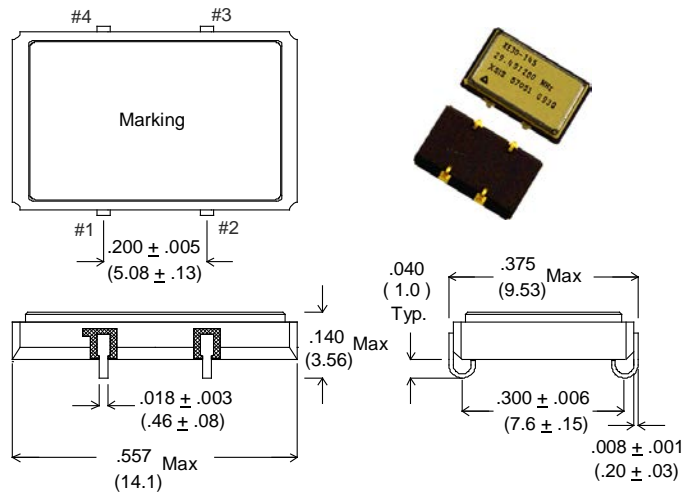
- High Shock & Vibration Applications
- Navigation Systems
- Aerospace Instrumentation
- Benign Space Applications
- Gun Launched Munitions

Package Specifications & Outline:

- Package : Ceramic 90% AL₂ O₃
- Seal: Hermetic – Resistance Welded
- Weight: 0.8 Gms typical, 1.0 Gms Max.
- Thermal Resistance, Junction to Case (θ_{JC}): 30 °C / Watt
- Solder Reflow, Temp./Time: 260 °C, 10 Secs. Max.
- Lead Material & Finish: Kovar, 50 to 80 μ inches gold over 100 to 250 μ inches Nickel

Hot Solder Tinning per MIL-PRF-55310 is optional at additional cost.

Contact Xsis Electronics at xis@xis.com for any special requirements.



Dimensions: Inches (mm)

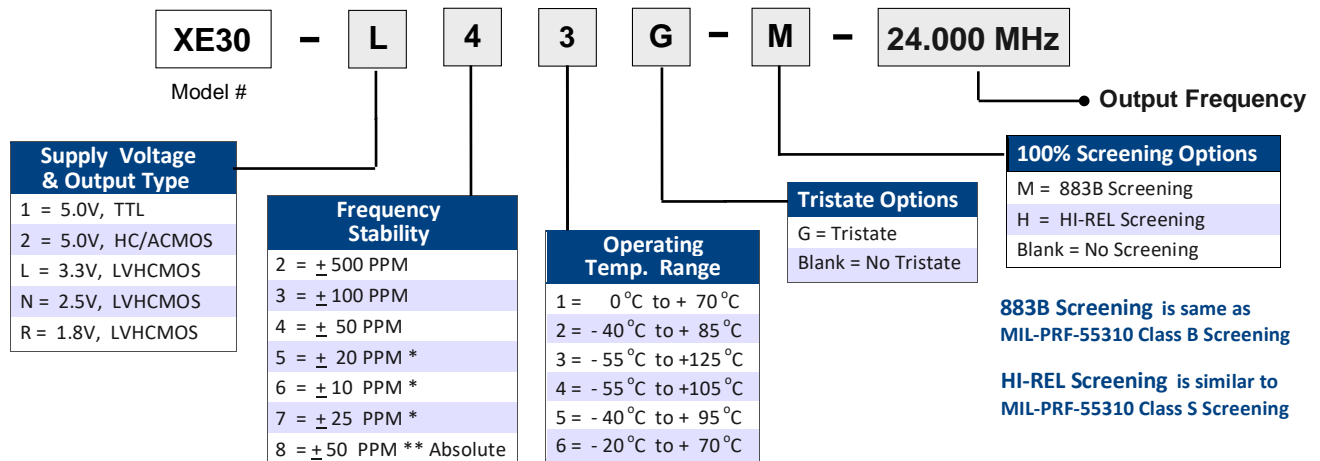
LEAD#	FUNCTION
1	Tristate or NC
2	GND/CASE
3	OUTPUT
4	VDD

Tristate Input: A “Low” level at the input disables the Output into a high impedance state.

Tristate Input has internal pull-up. It can be left floating or connected to Vdd.

ORDERING INFORMATION (Please build your part number from options below) :

P/N EXAMPLE: XE30 - L43G - 883B - 24.000 MHz = 3.3V LVHCMOS, ± 50 PPM over -55 °C to +125 °C, Tristate Output, 883B Screening and 24.000 MHz



* Frequency Stability Options 5, 6 & 7 are not available for all operating temperature ranges.

** Option 8 provides ± 50 PPM Absolute accuracy with reference to the Nominal Frequency includes initial accuracy at 25 °C and ± 10% Supply Voltage and ± 10% load variation.

883B Screening is same as MIL-PRF-55310 Class B Screening

HI-REL Screening is similar to MIL-PRF-55310 Class S Screening



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Electrical Specifications, 5V TTL & 5V HC/ACMOS Oscillators

Parameter	5 V TTL	5 V HC/ACMOS
Output Frequency Range	450 KHz - 100 MHz	450 KHz - 100 MHz
Frequency Accuracy at +25°C	± 15 PPM	± 15 PPM
Frequency Stability Vs Temperature	See Ordering Information on Page 1	
Operating Temperature Range	See Ordering Information on Page 1	
Supply Voltage (Vdd)	+ 5 VDC ± 10%	+ 5 VDC ± 10%
Input Current (no Load)	450 KHz - < 5 MHz 10 mA Max. 5 MHz - < 20 MHz 20 mA Max. 20 MHz - < 40 MHz 30 mA Max. 40 MHz - < 60 MHz 40 mA Max. 60 MHz - 100 MHz 60 mA Max.	450 KHz - < 5 MHz 10 mA Max. 5 MHz - < 20 MHz 20 mA Max. 20 MHz - < 40 MHz 30 mA Max. 40 MHz - < 60 MHz 40 mA Max. 60 MHz - 100 MHz 60 mA Max.
Output Waveform	Square Wave	Square Wave
Output Duty Cycle	60/40% Max. (at 1.4V Output Level)	< 40 MHz 55/45% Max. ≥ 40 MHz 60/40% Max. (at 50% Output Level)
Output High Level	2.5 V Min.	0.9 Vdd Min.
Output Low Level	0.5 V Max.	0.1 Vdd Max.
Output Load	TTL, 10 Loads Max. 50 pF Max. for <50 MHz	10K // 15 pF 50 pF Max. for <50 MHz
Rise & Fall Times (Typical Load)	< 30 MHz 6 nS Max. ≥ 30 MHz 3 nS Max. (0.8 to 2.0V Output Levels)	< 30 MHz 6 nS Max. ≥ 30 MHz 3 nS Max. (10% to 90% Output Levels)
Tristate	Tristate Input ≥ 2.2V or Open : Normal Output Tristate Input ≤ 0.8V: High Impedance	
Start-Up Time	5 mS Max.	5 mS Max.
Phase Jitter (10 KHz - 20 MHz Integ.)	0.15 pS rms Typical	0.15 pS rms Typical
Freq. Stability Vs Supply Voltage	± 4 PPM Max. for ± 10% change in Supply Voltage	
Aging at 70 °C	± 3 PPM Max. first year, ± 2 PPM Max. per year thereafter	
Absolute Maximum Applied Voltage	+ 7VDC	+ 7VDC
Storage Temperature	-65 °C to +125 °C	-65 °C to +125 °C

For special requirements, such as, tighter output symmetry, faster start-up time, PIND screening, etc., please contact Xsis Electronics at xisis@xisis.com or call us at 913-631-0448.



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5.0V TTL, 5.0V HC/ACMOS, 3.3V, 2.5V & 1.8V LVHCMOS

Electrical Specifications, 3.3V, 2.5V & 1.8V LVHCMOS Oscillators

Parameter	3.3V	2.5V	1.8V
Output Frequency Range	250 KHz to 160 MHz	250 KHz to 135 MHz	250 KHz to 100 MHz
Frequency Accuracy at +25 °C	± 15 PPM		
Frequency Stability Vs Temperature	See Ordering Information on Page 1		
Operating Temperature Range	See Ordering Information on Page 1		
Supply Voltage (Vdd)	3.3V ± 10%	2.5V ± 10%	1.8V ± 10%
Input Current (no Load)	250 KHz - 8 MHz 3 mA Max. 8.1 MHz - 16 MHz 6 mA Max. 16.1 MHz - 32 MHz 10 mA Max. 32.1 MHz - 60 MHz 20 mA Max. 60.1 MHz - 100 MHz 30 mA Max. 100.1 MHz - 130 MHz 40 mA Max. 130.1 MHz - 160 MHz 50 mA Max	250 KHz - 8 MHz 3 mA Max. 8.1 MHz - 16 MHz 4 mA Max. 16.1 MHz - 32 MHz 8 mA Max. 32.1 MHz - 60 MHz 15 mA Max. 60.1 MHz - 100 MHz 20 mA Max. 100.1 MHz - 135 MHz 30 mA Max.	250 KHz - 8 MHz 3 mA Max. 8.1 MHz - 16 MHz 4 mA Max. 16.1 MHz - 32 MHz 6 mA Max. 32.1 MHz - 60 MHz 10 mA Max. 60.1 MHz - 85 MHz 20 mA Max. 85.1 MHz - 100 MHz 25 mA Max.
Output Waveform	Square Wave, LVHCMOS Compatible		
Output Duty Cycle (at 50% Output Level)	< 40 MHz 55/45% ≥ 40 MHz 60/40%	< 40 MHz 55/45% ≥ 40 MHz 60/40%	< 40 MHz 55/45% ≥ 40 MHz 60/40%
Output High Level	0.9 Vdd Min.		
Output Low Level	0.1 Vdd Max.		
Output Load	10K // 15 pF		
Rise & Fall Times (Typical Load)	< 40 MHz 6 nS Max. ≥ 40 MHz 3 nS Max. (10% to 90% Output Levels)		
Tristate	Tristate Input ≥ 0.7 Vdd or Open : Normal Output Tristate Input ≤ 0.3 Vdd: High Impedance		
Start-Up Time	5 mS Max.		
Phase Jitter (10 KHz - 20 MHz Integ.)	0.15 pS rms Typical		
Freq. Stability Vs Supply Voltage	± 4 PPM Max. for ± 10% change in Supply Voltage		
Aging at 70 °C	± 3 PPM Max. first year, ± 2 PPM Max. per year thereafter		
Absolute Maximum Applied Voltage	+5.0 VDC		
Storage Temperature	-65 °C to +125 °C		

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Packaging:

Standard packaging is in ESD protective enclosed tray. Tape & Reel packaging is available at additional cost.

Thermal Characteristics:

Junction to case Thermal Constant (θ_{JC}): 30 °C / Watt

Junction to Ambient (Device floating in free air) Thermal Constant (θ_{JA}): 110 °C / Watt

Hi-Rel Screening:

When HI-REL option is selected, Xsis Oscillators are subjected to 100% screening similar to Class “S” screening in accordance with MIL-PRF-55310. Refer to www.xsis.com additional details about HI-REL screening.

Typical Phase Noise (dbc/Hz):

	10 Hz	100 Hz	1 KHz	10 KHz	100 KHz	1 MHz
10 MHz	-109	-140	-157	-162	-163	-164
25 MHz	-100	-127	-151	-158	-160	-162
50 MHz	-89	-117	-148	-157	-159	-160
96 MHz	-80	-107	-139	-151	-156	-158
100 MHz	-77	-104	-133	-145	-151	-155

Environmental Specifications:

XE30-100 series oscillators are designed to meet or exceed the Environmental tests specified below. Customized screening and environmental testing are also available to meet your special requirements.

Test	Test Conditions
Vibration	0.06” DA, 30 G peak, 10 - 2000 Hz, MIL-STD-202, Method 204, Cond. G
Shock	1500 G, 0.5 mS, half-Sine, MIL-STD-883, Method 2002, Cond. B
Temperature Cycling	MIL-STD-883, Method 1010, Cond. C
Thermal Shock	MIL-STD-202, Method 107, Cond. B
Seal (Fine and Gross)	MIL-STD-883, Method 1014 Cond. A & C
Burn-in	160 Hours, 125 °C, Nominal Supply Voltage & Load
Frequency Aging	30 days at 70 °C \pm 1.5 PPM Max., \pm 3 PPM Max. first year, \pm 2 PPM Max. per year thereafter
Altitude	MIL-STD-202, Method 105, Cond. C
Constant Acceleration	MIL-STD-883, Method 2001, 5000 G
Moisture Resistance	MIL-STD-202, Method 106, Vibration Sub Cycle Omitted
Solderability	MIL-STD-202, Method 208
Resistance to Soldering Heat	MIL-STD-202, Method 210, Cond B. or C as applicable
Resistance to Solvents	MIL-STD-202, Method 215
Internal Water Vapor Content	MIL-STD-883, Method 1018
ESD Classification	MIL-STD-883, Method 3015, Class 1C, HBM 1000 to 1999
Moisture Sensitivity Level	J-STD-020, MSL=1

